

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

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Title of Invention

High Capacity and High Rate Batteries

Application Number:

10/624226

Confirmation Number:

6964

First Named Applicant:

Attorney Docket Number: 3132.02US02

Dania Ghantous

Search string:

(3406228 or 3483110 or 4048290 or 4548798

or 4830940 or 4964877 or 5039452 or 5053580 or 5160664 or 5221453 or 5298349 or 5389472 or 5427763 or 5435874 or 5453261 or 5458997 or 5498494 or 5516340 or 5543249 or 5545496 or 5545497 or 5549880 or 5558680 or 5571640 or 4246327 or 5580683 or 5639577 or 5670276 or 5695892 or 5766797 or 5770126 or 5955218

or 6027827 or 6096447 or 6106798 or 6130005

or 5952125).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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Signature

Examiner Name	Date
John	12-5-06

APP_ID=10624226 Page 2 of 2

Substitute for form 1449/PTO					Complete if Known						
					Application Number 10/624,226						
INFORMATION DISCLOSURE					Fil	ling Date	July 28, 2003				
OVPE STATEMENT BY APPLICANT (Use as many sheets as necessary)				First Named Inventor		GH.	ANTOUS et al.				
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EXAMINER	Cite	Foreign Patent Document			Publication Date						
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